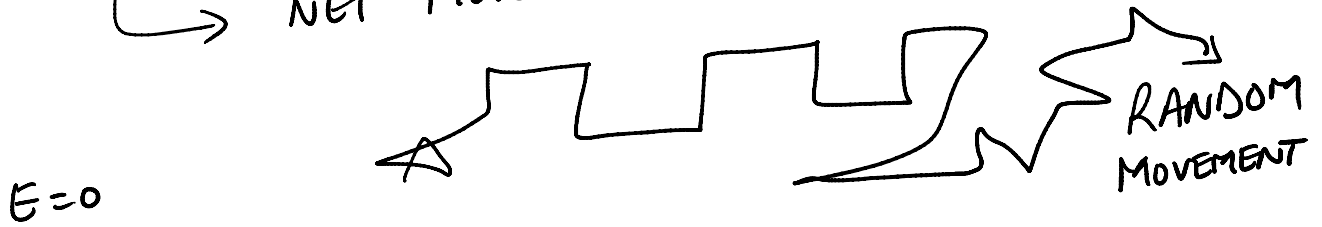


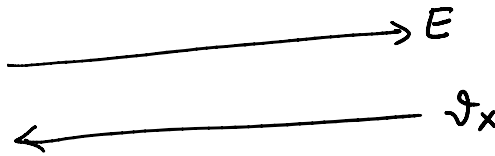
LECTURE -10

CARRIER DRIFT IN SEMI CONDUCTORS

DRIFT → APPLIED OR DEVELOPED E FIELD
 ↳ NET MOVEMENT OF CHARGE DUE TO E



E FINITE



ELECTRONS MOVE
 IN A DIRECTION
 WITH A VELOCITY
 v_x

ELECTRONS

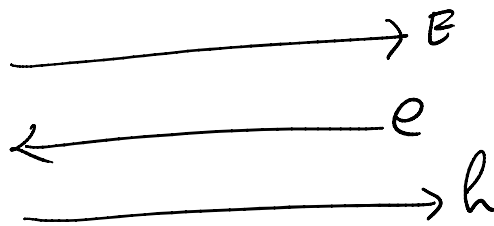
$$v = -\mu_n E$$

OPPOSITE DIRECTION
 w.r.t E

HOLES

$$v = \mu_p E$$

(SAME DIRECTION)



$\mu_n \rightarrow$ MOBILITY OF ELECTRONS
 $\mu_p \rightarrow$ " " HOLES

} UNITS
cm²/Vs

DEFINE $J \Rightarrow$ CURRENT DENSITY A/cm²

$$J_n = -q n_0 (-\mu_n E) = q n_0 \mu_n E$$

$$J_p = +q p_0 (\mu_p E) = q p_0 \mu_p E$$

$$\text{TOTAL } J = J_n + J_p$$

$$= q (n_0 \mu_n + p_0 \mu_p) E = \sigma E$$

$\sigma \rightarrow$ CONDUCTIVITY

$$\sigma = q (n_0 \mu_n + p_0 \mu_p) \quad (\Omega \text{cm})^{-1}$$

MOBILITY \rightarrow MEASURE OF HOW EASILY THE CARRIERS MOVE THROUGH THE MATERIAL

N AND P HAVE DIFFERENT
QUANTUM MECHANICAL ENVIRONMENTS

$$\mu_n \neq \mu_p$$

* DRIFT CURRENT IS CAUSED BY E

* $\mu_n > \mu_p$ \because ELECTRONS MOVE
EASILY THAN HOLES

* $\mu_n (N_{\text{DOPANTS}} = 0) > \mu_n (N_{\text{DOPANTS}} > 0)$

$\mu_p (N_{\text{DOPANTS}} = 0) > \mu_p (N_{\text{DOPANTS}} > 0)$

\therefore INCREASING THE CONCENTRATION DECREASES
 μ

CARRIER DIFFUSION

→ NET MOVEMENT OF CHARGE
DUE TO CONCENTRATION GRADIENT

→ MOVEMENT FROM HIGH CONCENTRATION
TO LOW CONCENTRATION

ID CASE $J_n = (-q) (D_n) \left(-\frac{dn}{dx}\right)$
 $= q D_n \frac{dn}{dx}$

* J_n IS POSITIVE → CURRENT IS IN THE
SAME DIRECTION AS GRADIENT

$$\begin{aligned} \bar{J}_p &= q D_p \left(-\frac{dp}{dx} \right) \\ &= -q D_p \frac{dp}{dx} \end{aligned}$$

* \bar{J}_p IS NEGATIVE, CURRENT IS IN THE OPPOSITE DIRECTION AS THE GRADIENT

$D_n, D_p \rightarrow$ DIFFUSION COEFFICIENTS cm^2/s

$$J = q D_n \frac{dn}{dx} - q D_p \frac{dp}{dx} \quad \left. \vphantom{J} \right\} \text{1-D CASE!}$$

$$\begin{aligned} \frac{D_n}{\mu_n} &= \frac{kT}{q} \\ \frac{D_p}{\mu_p} &= \frac{kT}{q} \end{aligned}$$

~~D~~
D IS RELATED TO μ